

Spec. #: SB1-21201

SB1-355-1-10

Microchip Laser

MAIN FEATURES

- 355 nm
- < 1.3 ns</p>
- > 1 uJ
- Single Longitudinal Mode
- All-In-One Miniature Design

Technical Specifications		
Drimen (Output Mayalen ath		
Primary Output Wavelength	355	nm
Pulse Repetition Rate	10	kHz
Pulse energy	>1	uJ
Pulse Width	< 1.3	ns
Peak Power	> 0.8	kW
Short Term Output Energy Instability	< 3 %	
(St.Dev. Over > 10000 samples)		
Long Term Output Power Instability	< 5 %	
(Power log over 24 hours)		
Beam Quality (M ²)	< 1.5	
Output Beam Diameter at Exit		
Aperture (1/e2) without beam	< 1	mm
expander		
Secondary Output Wavelength	1064nm and 532nm (collinear to 355nm beam)	
Beam Ellipticity (axes ratio)	> 0.80	
Warm Up time after cold start	< 5	min
Power Consumption	< 20	W
Mechanical Package	SB1	
Operational Temperature Range	+10°C to +40°C	
Storage Temperature Range	-20°C to +60°C	

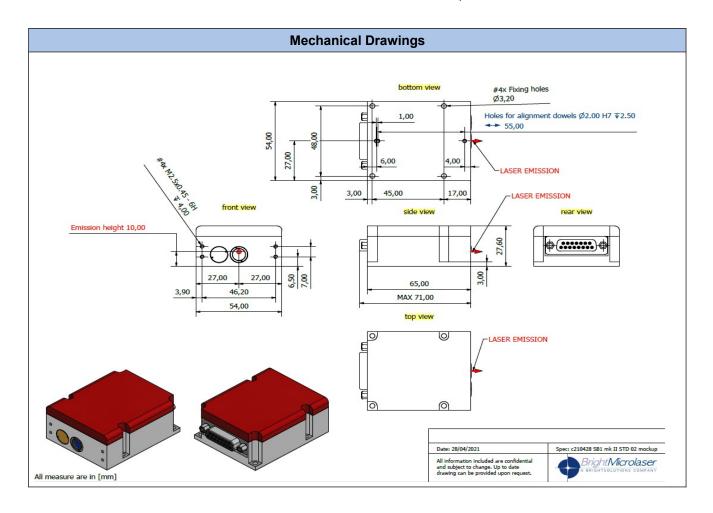
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Updated data sheets can be provided on request.

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For further details, please contact your local **Bright Microlaser** sales representative or visit our website at www.brightmicrolaser.com





Options Available:

- Beam Expander and Collimator
- Heat-sink
- Development kit
- Quick start/evaluation kit

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